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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/747,209	12/22/2000	Wei-Fan Chen	B-4068 618463-2	1081	
75	590 06/11/2003				
LADAS AND PARRY 5670 WILSHIRE BOULEVARD # 2100			EXAMINER		
			FARAHANI, DANA		
Los Angeles, CA 90036-5679			ART UNIT	PAPER NUMBER	
			2814		
			DATE MAILED: 06/11/2003	DATE MAILED: 06/11/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

į		Application No.	Applicant(s)				
Office Action Summary		09/747,209	CHEN, WEI-FAN				
		Examiner	Art Unit				
		Dana Farahani	2814				
Period fo	The MAILING DATE of this communication app or Reply	pears on the cover sheet	with the correspondence address				
THE I - Exter after - If the - If NC - Failu - Any r	ORTENED STATUTORY PERIOD FOR REPL' MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.1: SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period of the reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may y within the statutory minimum of t will apply and will expire SIX (6) My, cause the application to become	a reply be timely filed nirty (30) days will be considered timely. DNTHS from the mailing date of this communication. ABANDONED (35 U.S.C. § 133).				
1)🛛	Responsive to communication(s) filed on 24 !	<u>March 2003</u> .					
2a) <u></u> □	This action is FINAL . 2b)⊠ Th	is action is non-final.					
3)□	Since this application is in condition for allowa closed in accordance with the practice under						
·	ion of Claims						
•	Claim(s) <u>1-37</u> is/are pending in the application						
	4a) Of the above claim(s) is/are withdraw	wn from consideration.					
	Claim(s) is/are allowed.						
	Claim(s) <u>1-37</u> is/are rejected.						
·	Claim(s) is/are objected to.						
•	Claim(s) are subject to restriction and/o ion Papers	r election requirement.					
	The specification is objected to by the Examine	r.					
•	The drawing(s) filed on is/are: a)☐ accep		the Examiner.				
,	Applicant may not request that any objection to the						
11)[The proposed drawing correction filed on	_ is: a)☐ approved b)☐	disapproved by the Examiner.				
	If approved, corrected drawings are required in re	oly to this Office action.					
12) 🔲	The oath or declaration is objected to by the Ex	aminer.					
Priority u	under 35 U.S.C. §§ 119 and 120						
13)	Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C	s. § 119(a)-(d) or (f).				
a) ☐ All b) ☐ Some * c) ☐ None of:							
	1. Certified copies of the priority documents have been received.						
	2. Certified copies of the priority documents have been received in Application No						
* 5	3. Copies of the certified copies of the prior application from the International Buse the attached detailed Office action for a list	reau (PCT Rule 17.2(a))).				
	Acknowledgment is made of a claim for domesti	•	1				
а) ☐ The translation of the foreign language pro Acknowledgment is made of a claim for domest	ovisional application has	been received.				
Attachmen	-	io priority under 55 5.0.	5. 33 120 dildiol 121.				
1) Notice	ee of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice	w Summary (PTO-413) Paper No(s) of Informal Patent Application (PTO-152)				

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

2. Claims 1-5, 7-9, 11, 12, 14-17, 18-20, 22, 24, 26, 28-30, 32-35, and 37 are rejected under 35 U.S.C. 102(e) as being anticipated by Yu (U.S. Patent 6,476,422).

Regarding claims 1, 11, 17, and 34, Yu discloses in figure 7 (this figure is used to address the subsequent rejections that follow) an electrostatic discharge protection circuit with high trigger current, coupled to a node 46 and a reference potential shown at the right of the substrate 30, the electrostatic discharge protection circuit comprising: a substrate 30 of a first conductivity type, coupled to the reference potential; a well region 32 having a second conductivity type, formed on the substrate and coupled to the node 46; a first doping region 36 having the first conductivity type floated on the well region;

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and a second doping region 38 having the second conductivity type, disposed on the substrate and electrically coupled to the reference potential.

Regarding claims 2 and 18, Yu discloses the electrostatic discharge protection circuit further comprises a third doping area 34 having the second conductivity type, disposed in the well region, electrically coupled to the node, for forming an ohmic connection at the well region.

Regarding claims 3 and 19, Yu discloses the electrostatic discharge protection circuit, further comprises a forth doping region 40 having the first conductivity type, disposed at the surface of the substrate near said well region, electrically coupled to the reference potential.

Regarding claims 4, 14-16, 32-33, and 37, Yu discloses the electrostatic discharge protection circuit wherein the first conductivity is p-type, and the second conductivity is n-type.

Regarding claims 5, 20, and 26, Yu discloses the electrostatic discharge protection circuit, wherein the electrostatic discharge circuit further comprises a fifth conductivity type 54 having the second conductivity type, disposed at the conjunction of the well region and the substrate.

Regarding claims 7-9, 12, 22, 24, 28-30, and 35, Yu discloses the electrostatic discharge protection circuit, wherein the electrostatic discharge protection circuit further comprises a MOS transistor 58 disposed on the substrate and two source/drain regions 54 and 38, wherein one of source/drain regions is electrically coupled to the well region,

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while the other of the source/drain regions, together with the gate, is electrically coupled to the reference potential.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 6, 21, and 27 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yu, as applied to claims 1, 11, 17, and 34 above, and further in view of Liu et al., hereinafter Liu (U.S. Patent 6,455,898).

Yu discloses the claimed invention, as discussed above, except for a field oxide region adjacent to the fifth region.

Liu discloses a filed oxide region, 520 of figure 5B, for the electrostatic discharge protection circuit shown in the figure. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to include a field oxide region in the Yu structure in order to realize surface isolation of the fifth region in figure 6 of the Yu reference, and the other surface regions shown in the figure.

5. Claims 10, 13, 25, 31, and 36 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yu as applied to claims 1, 11, 17, and 34 above, and further in view of Yu (U.S. Patent 5,869,873), hereinafter '873 patent.

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Yu discloses the claimed invention, as discussed above, except for a resistor and capacitors with the connections specified in those claims.

'873 patent discloses, in figures 5 and 6, The electrostatic discharge protection circuit, wherein the electrostatic discharge protection circuit further comprises: a MOS transistor 55 having the first conductivity type, formed on the substrate, comprising a gate 554, and two source/drain regions 53 and 54, wherein one source/drain region is electrically coupled to a N-well region, and the other source/drain region is electrically coupled to the reference potential; a resistor R, its two ends electrically coupled to the gate and the reference potential, respectively; and a capacitor C of figure 6, its two ends electrically coupled to the gate and the node, respectively. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to include the resistor and capacitor of the '873 patent in Yu's structure in order to make the ESD apparatus of the Yu reference to control the relationship between the coupling voltage of the device and the pad.

Response to Arguments

6. Applicant's arguments filed 3/24/03, with respect to the rejections of claims 1-37 have been fully considered and are persuasive. Therefore, the rejection has been withdrawn. However, upon further consideration, new grounds of rejections are made in this Office Action.

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dana Farahani whose telephone number is (703)305-1914. The examiner can normally be reached on M-F 9:00AM - 6:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M Fahmy can be reached on (703)308-4918. The fax phone numbers for the organization where this application or proceeding is assigned are (703)872-9318 for regular communications and (703)872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0956.

D. Farahani June 2, 2003

LONG PHAM
PRIMARY EXAMINER